





Features

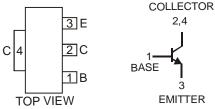
- Epitaxial Planar Die Construction
- Complementary PNP Type Available (2DB1188)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.072 grams (approximate)







Schematic and Pin Configuration

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	40	V
Collector-Emitter Voltage	V _{CEO}	32	V
Emitter-Base Voltage	V_{EBO}	5	V
Peak Pulse Current	I _{CM}	2.5	A
Continuous Collector Current	Ic	2	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T _A = 25°C	P _D	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T _A = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150	°C

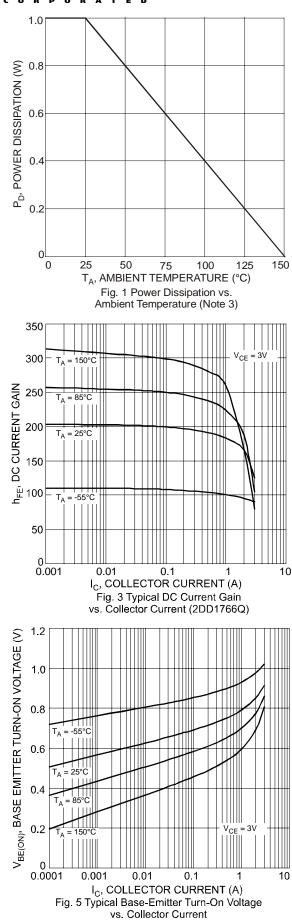
Electrical Characteristics @T_A = 25°C unless otherwise specified

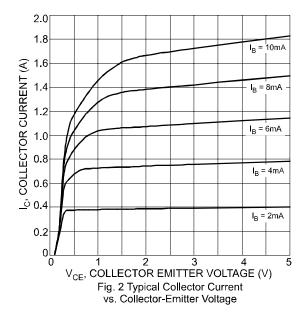
Characteristic		Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)							•
Collector-Base Breakdown Voltage		V _{(BR)CBO}	40	_	_	V	$I_C = 50 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage		$V_{(BR)CEO}$	32	_	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage		V _{(BR)EBO}	5	_	_	V	$I_E = 50 \mu A, I_C = 0$
Collector Cut-Off Current		I _{CBO}	_	_	1	μΑ	$V_{CB} = 20V, I_{E} = 0$
Emitter Cut-Off Current		I _{EBO}	_	_	1	μА	$V_{EB} = 4V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)							
Collector-Emitter Saturation Voltage		V _{CE(SAT)}		0.3	0.8	V	$I_C = 2A$, $I_B = 0.2A$
	2DD1766P	h _{FE}	82	_	180	_	
	2DD1766Q		120	_	270	_	$V_{CE} = 3V, I_{C} = 0.5A$
	2DD1766R		180	_	390	_	7
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency		f _T		220	_	MHz	$V_{CE} = 5V$, $I_E = -50mA$, $f = 100MHz$
Output Capacitance		C _{ob}	_	13	_	pF	$V_{CB} = 10V$, $I_E = 0$, $f = 1MHz$

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 3. Device mounted on FR-4 PCB; pad layout as shown on page 4 or in Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 4. Measured under pulsed conditions. Pulse width = $300\mu s$. Duty cycle $\leq 2\%$.







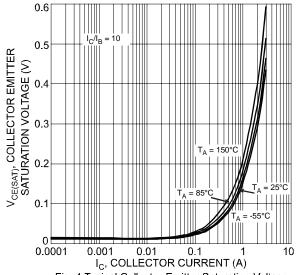


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

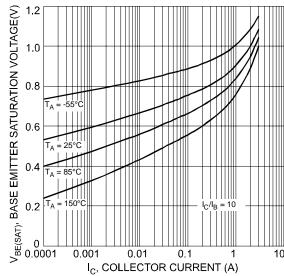
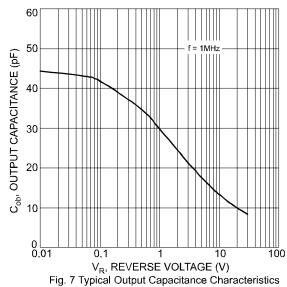


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current





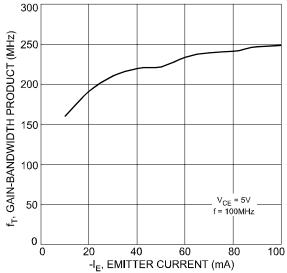


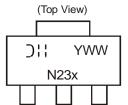
Fig. 8 Typical Gain-Bandwidth Product vs. Emitter Current

Ordering Information (Note 5)

Device	Packaging	Shipping
2DD1766P-13	SOT89-3L	2500/Tape & Reel
2DD1766Q-13	SOT89-3L	2500/Tape & Reel
2DD1766R-13	SOT89-3L	2500/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/ap02007.pdf.

Marking Information



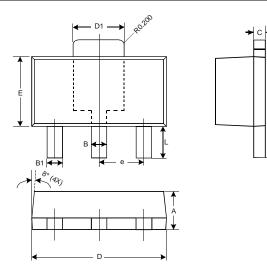
N23x = Product Type Marking Code: Where N23P = 2DD1766P

N23Q = 2DD1766Q N23Q = 2DD1766R

YWW = Date Code Marking
Y = Last digit of year ex: 7 = 2007

Y = Last digit of year ex: 7 = 2007 WW = Week code 01 - 52

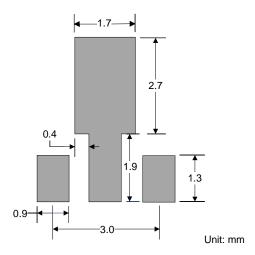
Package Outline Dimensions



	SOT89-3L					
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.45	0.55	0.50			
B1	0.37	0.47	0.42			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.50	1.70	1.60			
E	2.40	2.60	2.50			
е	_	_	1.50			
Н	3.95	4.25	4.10			
L	0.90	1.20	1.05			
All Dimensions in mm						



Suggested Pad Layout



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